

UNISONIC TECHNOLOGIES CO., LTD

1N50K-TA **Preliminary Power MOSFET**

1.3A, 500V **N-CHANNEL POWER MOSFET**

DESCRIPTION

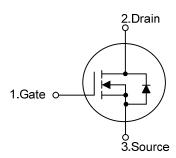
The UTC 1N50K-TA is an N-channel mode power MOSFET using UTC's advanced technology to provide customers with planar stripe and DMOS technology. This technology allows a minimum on-state resistance and superior switching performance. It also can withstand high energy pulse in the avalanche and commutation

The UTC 1N50K-TA is generally applied in high efficiency switch mode power supplies, active power factor correction and electronic lamp ballasts based on half bridge topology.



- * $R_{DS(ON)}$ < 6.00 @ V_{GS} =10V, I_{D} =0.65A
- * High Switching Speed
- * 100% Avalanche Tested

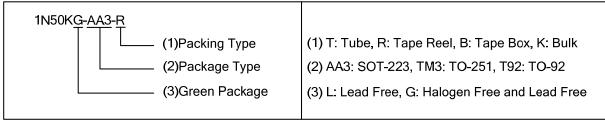


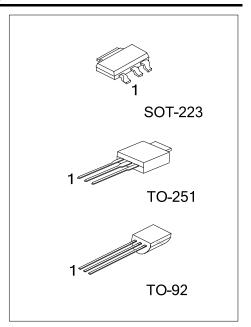


ORDERING INFORMATION

| Ordering Number | | Dookogo | Pin Assignment | | | Dooking | |
|-----------------|----------------|---------|----------------|---|---|-----------|--|
| Lead Free | Halogen Free | Package | 1 | 2 | 3 | Packing | |
| - | 1N50KG-AA3-T | SOT-223 | G | D | S | Tape Reel | |
| 1N50KL-TM3-T | 1N50KG-TM3-T | TO-251 | G | D | S | Tube | |
| 1N50KL-x-T92-B | 1N50KG-x-T92-B | TO-92 | G | D | S | Tape Box | |
| 1N50KL-x-T92-K | 1N50KG-x-T92-K | TO-92 | G | D | S | Bulk | |

Note: Pin Assignment: G: Gate D: Drain S: Source





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MARKING

| PACKAGE | MARKING |
|---------|--|
| SOT-223 | Lot Code 1N50KG Data Code 1 |
| TO-251 | UTC 1N50K□ Code L: Lead Free G: Halogen Free Data Code |
| TO-92 | UTC 1N50K L: Lead Free G: Halogen Free Data Code |

■ **ABSOLUTE MAXIMUM RATINGS** (T_C=25°C, unless otherwise specified)

| PARAMETER | | SYMBOL | RATINGS | UNIT |
|----------------------------|-----------------------------------|------------------|--------------|------|
| Drain-Source Voltage | | V_{DSS} | 500 | |
| Gate-Source Voltage | | V_{GSS} | ±30 | V |
| Drain Current | Continuous (T _C =25°C) | Ι _D | 1.3 (Note 2) | Α |
| Drain Current | Pulsed (Note 3) | I_{DM} | 5 (Note 2) | Α |
| Avalanche Current (Note 3) | | I_{AR} | 1.3 | Α |
| A decide Free | Single Pulsed (Note 4) | E_{AS} | 35 | mJ |
| Avalanche Energy | Repetitive (Note 5) | E_{AR} | 2.6 | mJ |
| | SOT-223 | | 1 | W |
| Power Dissipation | TO-251 | | 25 | W |
| | TO-92 | Б | 1.56 | W |
| | SOT-223 | P_D | 125 | W/°C |
| Derate above 25°C | TO-251 | | 0.2 | W/°C |
| | TO-92 | | 0.0125 | W/°C |
| Junction Temperature | · | TJ | +150 | °C |
| Storage Temperature | | T _{STG} | -55~+150 | |

Notes: 1. Absolute maximum ratings are those values beyond which the device could be permanently damaged. Absolute maximum ratings are stress ratings only and functional device operation is not implied.

- 2. Drain current limited by maximum junction temperature
- 3. Repetitive Rating: Pulse width limited by maximum junction temperature
- 4. L = 41mH, I_{AS} = 1.3A, V_{DD} = 50V, R_G = 27 Ω , Starting T_J = 25°C
- 5. $I_{SD} \le 1.5A$, di/dt $\le 200A/\mu s$, $V_{DD} \le BV_{DSS}$, Starting $T_J = 25^{\circ}C$

■ THERMAL RESISTANCES CHARACTERISTICS

| PARAMETER | | SYMBOL | RATINGS | UNIT | |
|---------------------|---------|-----------------|---------|------|--|
| Junction to Ambient | SOT-223 | | 150 | °C/W | |
| | TO-251 | θ_{JA} | 110 | °C/W | |
| | TO-92 | | 140 | °C/W | |
| Junction to Case | SOT-223 | | 125 | °C/W | |
| | TO-251 | θ _{JC} | 5 | °C/W | |
| | TO-92 | | 80 | °C/W | |

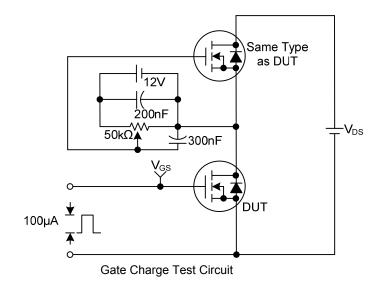
■ **ELECTRICAL CHARACTERISTICS** (T_C=25°C, unless otherwise specified)

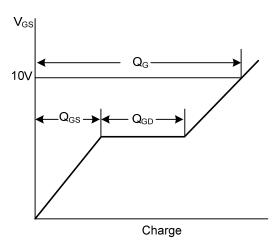
| PARAMETER | | SYMBOL | TEST CONDITIONS MIN | | TYP | MAX | UNIT | |
|---------------------------------------|-------------------|---------------------|---|-----|------|------|------|--|
| OFF CHARACTERISTICS | | | | | | | | |
| Drain-Source Breakdown Voltage | | BV _{DSS} | I _D =250μA, V _{GS} =0V | | | | V | |
| Drain-Source Leakage Current | | I _{DSS} | V _{DS} =500V, V _{GS} =0V | | | 1 | μA | |
| Gate- Source Leakage Current | Forward | less. | V_{GS} =+30V, V_{DS} =0V | | | +100 | nA | |
| | Reverse | | V _{GS} =-30V, V _{DS} =0V | | | -100 | nA | |
| ON CHARACTERISTICS | | | | | | | | |
| Gate Threshold Voltage | | $V_{GS(TH)}$ | $V_{DS}=V_{GS}$, $I_D=250\mu A$ | 3.0 | | 5.0 | V | |
| Static Drain-Source On-State Re | sistance | R _{DS(ON)} | V _{GS} =10V, I _D =0.65A | | 5 | 6 | Ω | |
| DYNAMIC PARAMETERS | | | | | | | | |
| Input Capacitance | Input Capacitance | | | | 180 | | pF | |
| Output Capacitance | | Coss | V_{GS} =0V, V_{DS} =25V, f=1.0MHz | | 30 | | pF | |
| Reverse Transfer Capacitance | | C_{RSS} | | | 12.5 | | pF | |
| SWITCHING PARAMETERS | | | | | | | | |
| Total Gate Charge | | Q_G | V =10V V =50V I =1.3A | | 11 | 15 | nC | |
| Gate to Source Charge | | Q_GS | V _{GS} =10V, V _{DS} =50V, I _D =1.3A | | 2.5 | | nC | |
| Gate to Drain Charge | | Q_GD | (Note 1, 2) | | 1 | | nC | |
| Turn-ON Delay Time | | $t_{D(ON)}$ | | | 37.5 | | ns | |
| Rise Time | | t_R | V _{DD} =30V, I _D =0.5A, R _G =25Ω (Note 1, 2) | | 20 | | ns | |
| Turn-OFF Delay Time | | t _{D(OFF)} | | | 53 | | ns | |
| Fall-Time | I-Time | | | | 12 | | ns | |
| SOURCE- DRAIN DIODE RATIN | IGS AND (| CHARACTERI | STICS | | ā. | | | |
| Maximum Body-Diode Continuous Current | | Is | | | | 1.3 | Α | |
| Maximum Body-Diode Pulsed Current | | I _{SM} | | | | 5.2 | Α | |
| Drain-Source Diode Forward Voltage | | V_{SD} | I _S =1.3A, V _{GS} =0V | | | 1.2 | V | |

Notes: 1. Pulse Test: Pulse width ≤ 300µs, Duty cycle ≤ 2%.

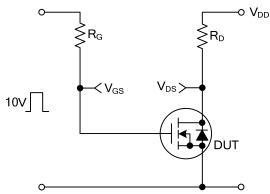
^{2.} Essentially independent of operating temperature.

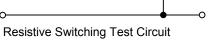
TEST CIRCUITS AND WAVEFORMS

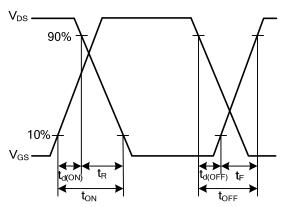




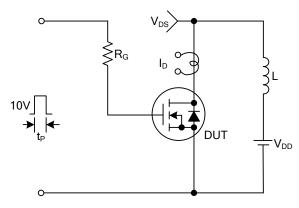
Gate Charge Waveforms



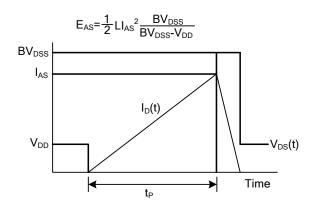




Resistive Switching Waveforms

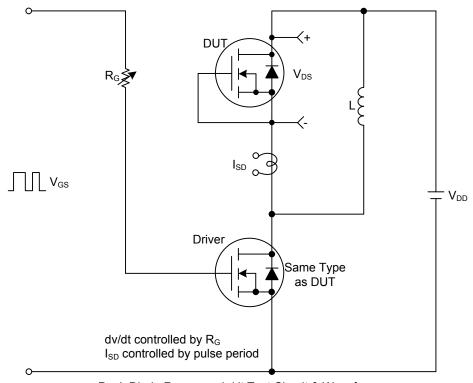


Unclamped Inductive Switching Test Circuit

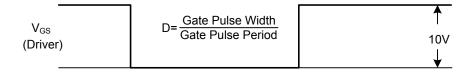


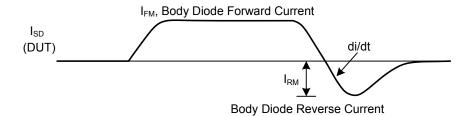
Unclamped Inductive Switching Waveforms

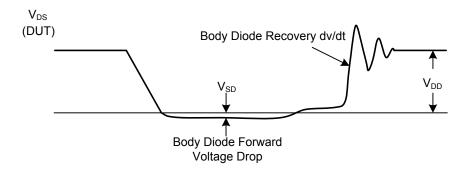
■ TEST CIRCUITS AND WAVEFORMS(Cont.)



Peak Diode Recovery dv/dt Test Circuit & Waveforms







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